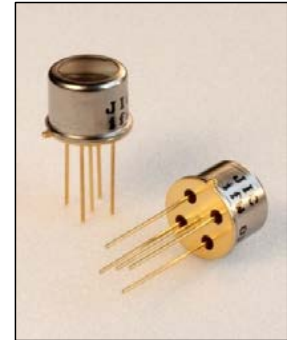


SiC-Photodiode 1,0 mm² with Voltage-Output JIC267 · JIC268 · JIC269

Characteristics :

- ◆ SiC photodiode with built-in transimpedance-amplifier
- ◆ voltage output U_{out} up to 5 V
- ◆ spectral range: 215 ... 358 nm
- ◆ active area: 1,0 mm²
- ◆ standard versions available in three transimpedance values:
 $R_F = 10 \text{ M}\Omega / 100 \text{ M}\Omega / 1000 \text{ M}\Omega$
- ◆ external adjustment of gain and bandwidth possible via sensor-pin
- ◆ dynamic range: 4 orders of magnitude
- ◆ single supply voltage
- ◆ sensor assembly isolated from case
- ◆ hermetically sealed TO5-package
- ◆ RoHS, REACH and WEEE conform



Applications :

- ◆ optical measurements in UV-range
- ◆ control of sterilization lamps
- ◆ flame control

Absolute Maximum Ratings :

- ◆ supply voltage U_S 5,5 V
- ◆ working temperature - 25 °C ... 85 °C
- ◆ storage temperature - 40 °C ... 100 °C
- ◆ soldering temperature (5s) 300 °C

Technical Specifications :

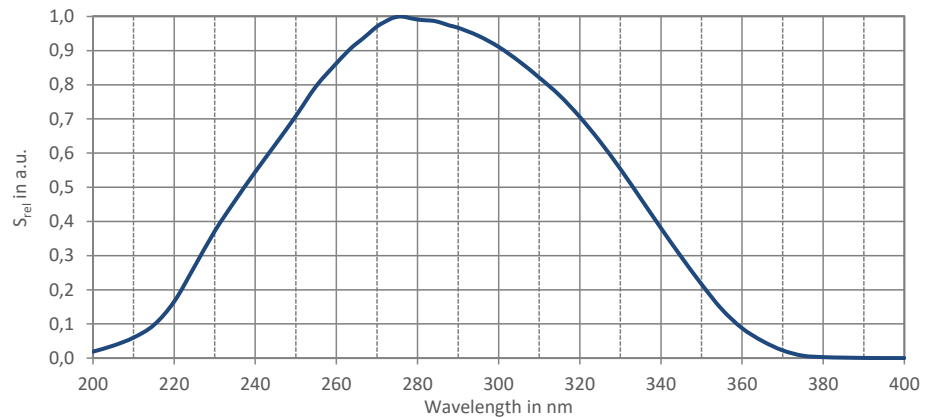
Parameter	Test-conditions	JIC267	JIC268	JIC269	Unit
transimpedance R_F		10	100	1.000	M Ω
dark offset voltage	$E = 0 \text{ lx}$	± 1	± 2	± 3	mV
noise voltage	$B = 1 \text{ kHz}$	1			mV _{rms}
max. spectral responsivity S_{max}	$\lambda = 276 \text{ nm}$	1,7	17	170	mV/nW
min. irradiance (sensitivity)	$U_{out} = 0,5 \text{ mV}$ $\lambda = 276 \text{ nm}$	294	29,4	2,94	$\mu\text{W}/\text{m}^2$
max. irradiance (saturation)	$U_{out, max} = 5 \text{ V}$ $\lambda = 276 \text{ nm}$	2.940	294	29,4	mW/m ²
rise time	10% / 90%	30	200	1100	μs
bandwidth	- 3 dB	10	1,5	0,3	kHz
saturation voltage $U_{out, max}$	$R_L = 2 \text{ k}\Omega$	+ 4,95 (+ 4,8)			V
short circuit current $I_{out, max}$		± 50			mA
supply voltage U_S		+ 2,7 ... + 5			V
current consumption I_S		750 (1100)			μA

common test conditions, if not specified otherwise: $T_A = 25 \text{ }^\circ\text{C}$, $U_S = +5 \text{ V}$
typical values, maximum values in brackets

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Relativ Spectral Responsivity S_{rel} :



Spectral Specifications :

Parameter	Test Conditions	JIC267	JIC268	JIC269	Unit
spectral range	λ_{short}	215			nm
	λ_{long}	358			nm
wavelength of max. responsivity λ_{Smax}	$S = S_{max}$	276			nm
max. spectral sensitivity S_{max}	$\lambda = 276$ nm	1,7	17	170	mV/nW
sensitivity for Hg-LP-lamps	$\lambda = 254$ nm	1,35	13,5	135	mV/nW
FOV	$S = 0,5 * S_{max}$	±48			degree

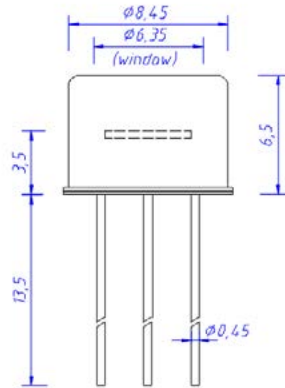
common test conditions, if not specified otherwise: $T_A = 25$ °C, typical values

Further Available Version:

Feature	Specification	ifw optronics parts	datasheet
wavelength range limitation	UV-A, UV-B, UV-C, etc...	JIC26xA/B/C	on request
smaller active area, lower price	0,1 mm ²	JIC227/228/229	on request
lens-caps (ball lens)	increased signal, reduced FOV	JIC269L	on request
diffusor optics	cosine-corrected signal reponse	JIC267D/268D/269D	on request

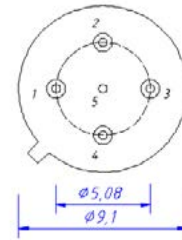
SiC-Photodiode 1,0 mm² with Voltage-Output JIC267 · JIC268 · JIC269

Case Dimensions



Pin Configuration:

- 1 R_F
- 2 Out
- 3 U_S
- 4 GND
- 5 Case



bottom view

Application Notes:

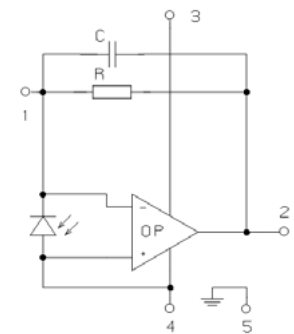
Gain and Bandwidth Adjustment

The transimpedance (voltage gain) can be reduced by paralleling the internal feedback resistor with external resistance over pin 1 "R_F" and pin 2 "Out"

In a similar way the bandwidth of the amplifier can be decreased by paralleling additional feedback-capacitance over pin 1 "R_F" and pin 2 "Out". Bandwidth limitation can be useful to decrease signal noise, or to guarantee amplifier stability when reducing the feedback resistance.

If an external resistor for gain reduction between pin 1 "R_F" and pin 2 "Out" is used, it is good practice to keep the connector-length as short as possible to reduce noise incoupling and capacitive interference.

If the internally adjusted gain is used only, it is good practice to cut pin 1 to omit noise incoupling.



Schematic: Internal circuit with pinout

Power-Supply

A well regulated supply voltage U_S should be used. There is no internal protection to prevent damage from voltage spikes or overvoltage situations.

It is good practice to use a decoupling capacitor (ca. 100nF, ceramic-type) between pin 3 "U_S" and pin 4 "GND" in proximity to the photodiode package.

Grounding

Depending on the application, the case pin 5 can be connected to ground potential of the circuit or the shielding environment. It is good practice to connect pin 5 "Case" to pin 4 "GND" if in doubt. Pin 5 should not be left floating.